- *EPIC*[™] (Enhanced-Performance Implanted CMOS) Process
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

These quadruple 2-line to 1-line data selectors/multiplexers are designed for 4.5-V to 5.5-V V_{CC} operation.

The 'AHCT157 devices feature a common strobe (\overline{G}) input. When the strobe is high, all outputs are low. When the strobe is low, a 4-bit word is selected from one of two sources and is routed to the four outputs. The devices provide true data.

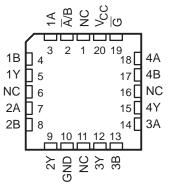
The SN54AHCT157 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AHCT157 is characterized for operation from -40°C to 85°C.

SN54AHCT157 J OR W PACKAGE
SN74AHCT157D, DB, DGV, N, OR PW PACKAGE

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	(IC)
A/B 1A 1B 1Y 2A 2B 2Y GND	1 2 3 4 5 6 7 8	16 15 14 13 12 11 10 9	, <u> </u>

SN54AHCT157 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE								
	OUTPUT							
G	Ā/B	Α	В	Y				
Н	Х	Х	Х	L				
L	L	L	Х	L				
L	L	Н	Х	н				
L	Н	Х	L	L				
L	Н	Х	Н	Н				



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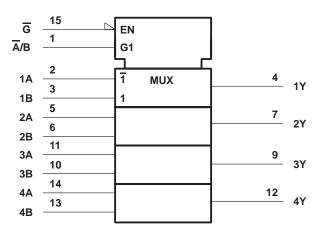
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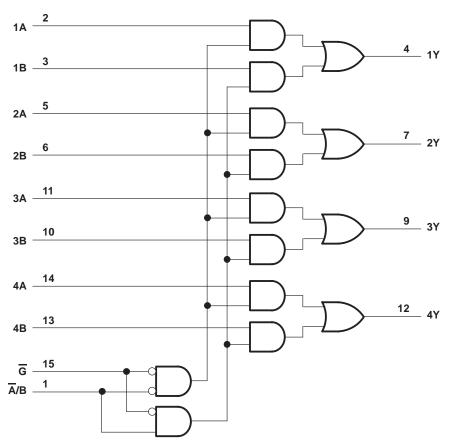
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logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.

logic diagram (positive logic)



Pin numbers shown are for the D, DB, DGV, J, N, PW, and W packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}
PW package 108°C/V Storage temperature range, T _{stg} –65°C to 150°C

⁺ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

		SN54AHCT157		SN74AHCT157		UNIT
		MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2	M	2		V
VIL	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
VO	Output voltage	0	Vcc	0	VCC	V
ЮН	High-level output current	200	-8		-8	mA
IOL	Low-level output current	30%	8		8	mA
$\Delta t/\Delta v$	Input transition rise or fall time	9	20		20	ns/V
ТА	Operating free-air temperature	-55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS Vcc		T _A = 25°C			SN54AHCT157		SN74AHCT157		UNIT	
PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
Maria	I _{OH} = -50 μA	4.5.1	4.4	4.5		4.4		4.4			
VOH	I _{OH} = -8 mA	4.5 V	3.94			3.8	Ņ	3.8		V	
Max	I _{OL} = 50 μA	451			0.1		0.1		0.1	V	
VOL	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44	V	
lj	$V_{I} = V_{CC}$ or GND	0 V to 5.5 V			±0.1	4	±1*		±1	μΑ	
ICC	$V_{I} = V_{CC} \text{ or GND}, I_{O} = 0$	5.5 V			2	nc	20		20	μΑ	
∆lcc‡	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35	Pho	1.5		1.5	mA	
Ci	$V_I = V_{CC}$ or GND	5 V		2	10				10	pF	

* On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0$ V.

[†] This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	Τ ₄	T _A = 25°C		SN54AH	CT157	SN74AH	CT157	UNIT				
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT				
^t PLH	A or B	Y	Ci - 15 pE		4.1**	6.4**	1**	7.5**	1	7.5	ns				
^t PHL	AUB	T	C _L = 15 pF		4.1**	6.4**	1**	7.5**	1	7.5	115				
^t PLH	Ā/B	Y	0. 45 pF		5.3**	8.1**	1**	9.5**	1	9.5	ns				
^t PHL	A/B	VB t	· ·	C _L = 15 pF		5.3**	8.1**	1**	9.5**	1	9.5	115			
^t PLH	G	V	v	v	~	Y	C _I = 15 pF		5.6**	8.6**	1**	210**	1	10	ns
^t PHL		I	0L = 13 pr		5.6**	8.6**	1**_<	10**	1	10	115				
^t PLH	A or B	A or B Y	C _I = 50 pF		5.6	8.7	0	10.8	1	9.8	ns				
^t PHL	AUB		CL = 50 pr		5.6	8.7	Q Q	10.8	1	9.8	115				
^t PLH	Ā/B	Y	C _I = 50 pF		6.8	10.4	Å 1	13.2	1	12	ns				
^t PLH		ſ	CL = 50 pr		6.8	10.4	1	13.2	1	12	115				
^t PLH	G	Y	C _I = 50 pF		7.1	11	1	13.5	1	12	20				
^t PHL	9	r	CL = 50 pr		7.1	11	1	13.5	1	12	ns				

** On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

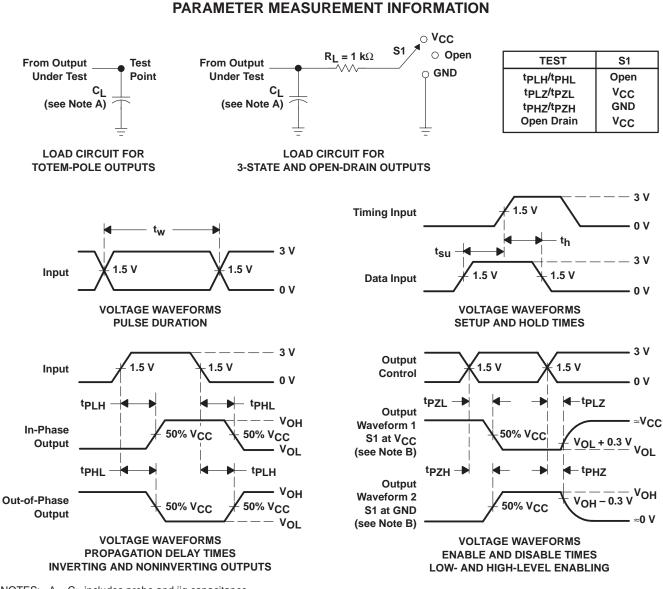
	PARAMETER	SN7	UNIT		
	PARAMETER				UNIT
VOL(P)	Quiet output, maximum dynamic V _{OL}		0.4	0.8	V
VOL(V)	Quiet output, minimum dynamic V _{OL}		-0.4	-0.8	V
VOH(V)	Quiet output, minimum dynamic V _{OH}		4.8		V
V _{IH(D)}	High-level dynamic input voltage	2			V
V _{IL(D)}	Low-level dynamic input voltage			0.8	V

NOTE 4: Characteristics are for surface-mount packages only.



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operating characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$									
	PARAMETER	TEST CO	ONDITIONS	TYP	UNIT				
Cpd	Power dissipation capacitance	No load,	f = 1 MHz	11	pF				



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f \leq 3 ns, t_f \leq 3 ns.

D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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